

FORM PTO-1449
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3000-0068

APPLICANT: Burgmair et al.

FILING DATE: August 4, 2006

SERIAL NO. 10/588,559

GROUP: 2814

EXAMINER: Diana C. Garrity

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT****U.S. PATENT DOCUMENTS**

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
/	B						
/	B						
/	C						
/	D						
/	E						
/	F						
/	G						

FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO
/D.G./	H	JP 08189870	7/23/1996	Japan	9	12	Yes-Abstract
/D.G./	I	JP 56100350	8/12/1981	Japan	27	30	Yes-Abstract
/D.G./	J	JP 63171355	7/15/1988	Japan	27	30	Yes-Abstract
/	K						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

EXAMINER INITIAL		
/D.G./	L	Matsushima Toshinori et al., "Organic-inorganic field effect transistor with SnI ₂ -based perovskite channel layer using vapour phase deposition technique," Proceedings of the SPIE-The International Society for Optical Engineering, 2003, Vol. 5217, Pages 43-54 (ABSTRACT) CAPLUS [online]
/D.G./	M	Sudholter, Ernst et al., "Modification of ISFETs by covalent anchoring of poly(hydroxyethylmethacrylate) hydrogel. Introduction of thermodynamically defined semiconductor-sensing membrane interface." Analytica Chimica Acta, 1990, Vol. 230, No. 1, Pages 59-65 (ABSTRACT) CAPLUS [online]
/	N	
/	O	
/	P	
/	Q	

EXAMINER

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DATE CONSIDERED

03/20/2009

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Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.